

RECEIVED

JAN 16 2003

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE  
TECHNOLOGY CENTER 2800

#14  
amdt B  
D. Smalls-Logan  
520.39251X00  
1-28-03

**Applicants:** S. YAMAGUCHI, et al.  
**Application No.:** 09/698,274  
**Filed:** October 30, 2000  
**For:** SEMICONDUCTOR DEVICE, METHOD OF MAKING THE  
SAME AND LIQUID CRYSTAL DISPLAY DEVICE  
**Art Group:** 2826  
**Examiner:** F. Abraham

**AMENDMENT**

Commissioner of Patents  
Washington, D.C. 20231

January 16, 2003

Sir:

In response to the Office Action mailed October 24, 2002, please amend the above-identified application as follows:

**IN THE CLAIMS:**

Please cancel Claims 4, 5, 8, 9, 10, 13, 14, 15, 32, 33 and 36 without prejudice or disclaimer.

Please amend Claims 6, 7 and 12 as follows:

B<sup>1</sup>  
6. (Amended) A thin-film semiconductor device comprising an insulator, a polycrystalline layer formed on said insulator, and a transistor comprising a source region, a drain region, a gate region, and a channel region formed at the surface portion of said polycrystalline layer, said polycrystalline layer comprising crystal grains of an element selected from the group of Type-IV elements and their alloys,